

U.S. PAT. & T.M. OFFICE  
01/14/02  
320DS

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PATENT NUMBER and  
ISSUE DATE

U.S. UTILITY Patent Application

APPLICATION:		CLASS		SUBCLASS		GAU		EXAMINER	
APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER				
10047323	01/14/2002	427	104	1762	Sang				
<b>**APPLICANTS:</b> Lampert William; Eiting Christopher; Smith Scott; Haas Trice;									
<b>**CONTINUING DATA VERIFIED:</b> THIS APPLN CLAIMS BENEFIT OF 60/265,167 01/30/2001									
<b>** FOREIGN APPLICATIONS VERIFIED:</b>									
PG-PUB		DO NOT PUBLISH <input checked="" type="checkbox"/>			RESCIND <input type="checkbox"/>				
Foreign priority claimed		<input type="checkbox"/> yes <input type="checkbox"/> no			ATTORNEY DOCKET NO				
35 USC 119 conditions met		<input type="checkbox"/> yes <input type="checkbox"/> no			AFD 504				
Verified and Acknowledged Examiners's initials									
TITLE : Method of growing homoepitaxial silicon carbide									

U.S. DEPT. OF COMM. PAT. & T.M.-PTO-436L (Rev. 12-94)

<b>NOTICE OF ALLOWANCE MAILED</b>		<b>CLAIMS ALLOWED</b>	
		Total Claims	Print Claim for 0.6
Assistant Examiner			
<b>ISSUE FEE</b>		<b>DRAWING</b>	
Amount Due	Date Paid	Sheets Drawg.	Figs. Drawg.
		Print Fig.	
<input checked="" type="checkbox"/> <b>TERMINAL DISCLAIMER</b>		Primary Examiner	
		Application Examiner	
		<b>PREPARED FOR ISSUE</b>	
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